NSN 5961-01-104-0179

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Inclosure Material:

Plastic

Overall Length:

Between 0.280 inches and 0.320 inches

Overall Width:

Between 0.360 inches and 0.410 inches

Mounting Facility Quantity:

1

Internal Configuration:

Field effect

Electrode Internally-electrically Connected To Case:

Drain

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 drain to gate voltage and 60.0 drain to source voltage

Current Rating Per Characteristic:

2.00 amperes drain current and 2.00 milliamperes gate current

Power Rating Per Characteristic:

2.1 watts total device dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius case

Terminal Type And Quantity:

3 tab w/wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

